

Product Description

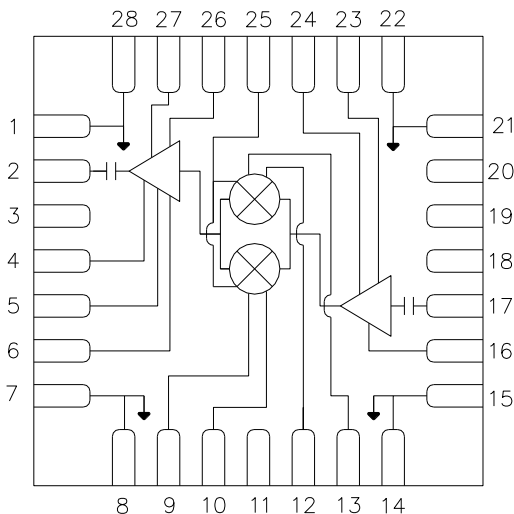
The QORVO TGC4510-SM is a K-Band image reject upconverter mixer with integrated x2 LO buffer amplifier and output variable gain amplifier. The TGC4510-SM outputs an RF frequency from 17.7 to 26.5 GHz using IF inputs from DC to 4.0 GHz and a corresponding LO frequency. It is designed using QORVO's pHEMT production process.

The TGC4510-SM typically provides 32 dBm of output TOI at -10 dBm input power per tone and has a conversion gain of 13 dB. Optional nulling of the LO can improve LO Isolation by 30 dB.

The TGC4510-SM is available in a low-cost, surface mount 28 lead 5x5mm QFN package and is ideally suited for Point-to-Point Radio, and K-Band VSAT Ground Terminal.

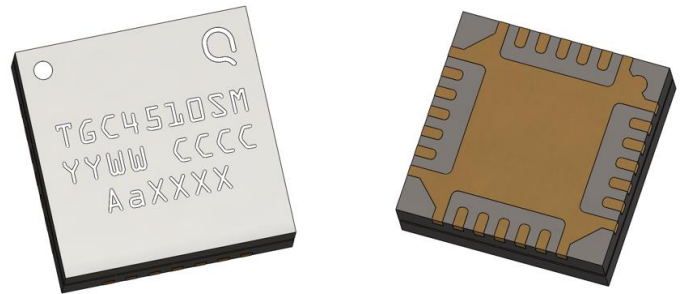
Lead-free and RoHS compliant.

Function Block Diagram



Applications

- VSAT Ground Terminal
- Point-to-Point Radio
- Millimeter Wave Communications



28-pin 5x5 mm QFN package

Product Features

- RF Frequency Range: 17.7 – 26.5 GHz
- IF Frequency: DC – 4.0 GHz
- LO Frequency: 6.85 – 15.25 GHz
- LO Input Power: 2 to 10 dBm
- Conversion Gain: 13 dB
- OTOI: 32 dBm at max gain
- Attenuation Range: 30 dB typical
- Bias 5.0 V, 360 mA, 3.3 V, 180 mA
- Package Dimensions: 5.0 x 5.0 x 1.3 mm

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

Ordering Information

Part No.	Description
TGC4510-SM	Ku-Band Upconverter
1119047	Shipping Tray, Qty 50
1098636	Tape and Reel, Qty 500
TGC4510-SMEVBLL	TGC4510-SM EVB LSB, Low IF Band, 1.3 to 2.45 GHz
TGC4510-SMEVBLH	TGC4510-SM EVB LSB, High IF Band, 2.5 to 4.0 GH
TGC4510-SMEVBUL	TGC4510-SM EVB USB, Low IF Band, 1.3 to 2.45 GHz
TGC4510-SMEVBUH	TGC4510-SM EVB USB, High IF Band, 2.5 to 4.0 GHz

Absolute Maximum Ratings

Parameter	Rating	Parameter	Rating
VDRF, VDLO1, VDLO23	+ 6 V	LO Nulling DC Voltage at IF1, IF2	-2 to +2 V
IDRF	390 mA	Input Power at LO Port, 50Ω, T = 25°C	15 dBm
IDLO1	190 mA	Input Power at IF Port, 50Ω, T = 25°C	18 dBm
IDLO23	300 mA	Power Dissipation, Pdiss	2 W
VGRF, VGLO, VGX	-3 to +1.5 V	Channel Temperature, Tch	200 °C
VCTRL1, VCTRL2	+ 3 to 0 V	Storage Temperature	-65 to 125°C

These are stress ratings only, functional operation of the device at these conditions is not implied. Extended application of Absolute Maximum Rating conditions may reduce device reliability. Operation of this device outside the parameter ranges given above may cause permanent damage.

Recommended Operating Conditions

Parameter ¹	Min	Typ	Max	Units	Parameter ¹	Min	Typ.	Max	Units
Operating Temp. Range	-40	+25	+85	°C	VGLO ³		-0.7		V
VDRF		5		V	VCTRL1, VCTRL2 (max gain) ⁴	-2		0	V
VGRF ²		-0.75		V	VCTRL1, VCTRL2 (min gain) ⁴	0		-2	V
IDRF		360		mA	Vi, Vq ⁵	-1		1	V
VDLO1, VDLO23		3.3		V	VGX		-1.2		V
IDLO1 + IDLO23	140	180	200	mA	LO Input Power	3	6	9	dBm

- 1 Electrical specification are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.
- 2 VGRF value is typical, can be adjusted to get required IDRF.
- 3 VGLO value is typical, can be adjusted to get required IDLO1+IDLO23.
- 4 VCTRL1 and VCTRL2 can be adjusted to achieve required conversion gain.
- 5 Vi and Vq can be adjusted to achieve required LO isolations, optional.

Electrical Specifications

Test conditions unless otherwise noted: VDLO1, VDLO23 = + 3.3 V, VGLO = -0.7 V, IDLO1 + IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = -1.2 V, T = 25 °C

Parameter	Conditions	Min	Typ	Max	Units
RF Frequency Range		17.7		26.5	GHz
LO Frequency Range		6.85		15.25	GHz
IF Frequency Range		0		4	GHz
Conversion Gain	1/ 17.7 GHz to 26.5 GHz		13		dB
Conversion Gain	1/ 17.7 GHz to 23.6 GHz	9.5	13	17.5	dB
Attenuation Range	2/		34		dB
SSB Noise Figure			15		dB
OIP3	17.7 GHz to 26.5 GHz	27.5	32		dBm
OIP3	17.7 GHz to 23.6 GHz	27.5	32		dBm
IIP3 at Minimum Gain			13		dBm
Image Rejection			15		dB
LO Isolation at RF Port	3/ Without external LO nulling voltage		-5		dB
LO Isolation at RF Port	3/ With external LO nulling voltage		25		dB
LO Return Loss			12		dB
RF Return Loss			11		dB

Notes:

1/ At Maximum gain.

2/ Maximum gain at VCTL1 = -2 V, VCTL2 = 0 V; Minimum gain at VCTL1 = 0 V, VCTL2 = -2 V

3/ LO Isolation = (Input Power at LO Port at LO Frequency) – (Output Power at RF port at 2xLO frequency)

Frequency Mapping

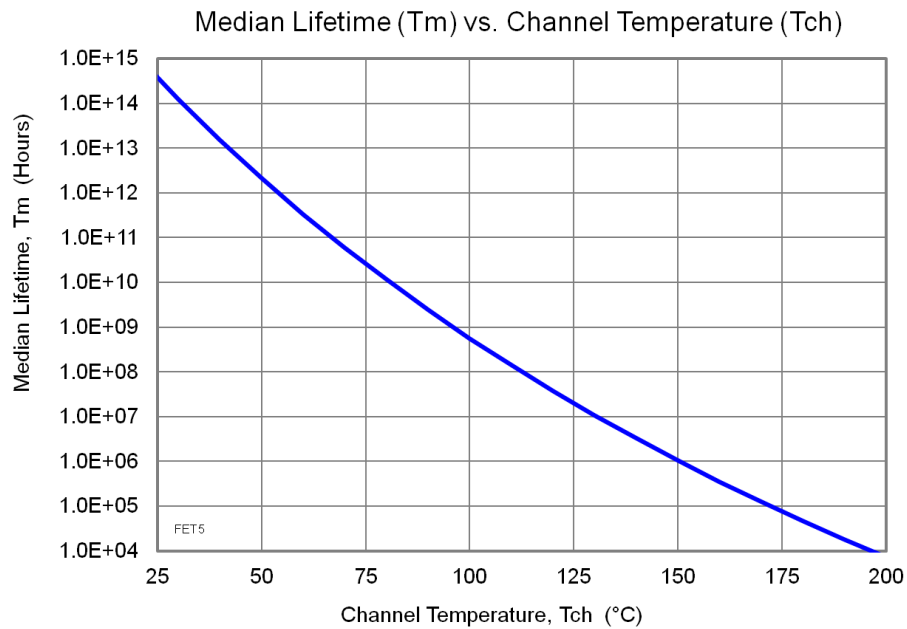
Lower Side Band Frequency Ranges		
IF Freq GHz	LO Freq GHz	RF Freq GHz
0.5	9-14	17.5-27.5
1.0	9-14	17-27
2.0	9-14	16-26
3.0	10-15	17-27
3.3	10-15.5	16.7-27.7
4.0	10-16	16-28

Upper Side Band Frequency Ranges		
IF Freq GHz	LO Freq GHz	RF Freq GHz
0.5	8-14	16.5-28.5
1.0	8-13	17-28
2.0	7-13	16-28
3.0	6.5-12	16-27
3.3	6.5-12	16.3-27.3
4.0	6.5-11	17-26

State	VCTRL1 V	VCTRL2 V
Max Gain	-2	0
Reduced Gain	-1.0	-1.0
Min Gain	0	-2

Thermal and Reliability Information

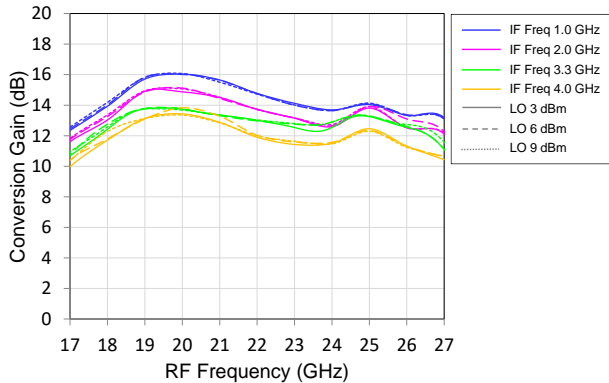
Parameter	Conditions	Rating
Thermal Resistance, θ_{JC} , measured to back of package	Tbase = 85 °C	θ_{JC} = 19.6 °C/W
Channel Temperature (Tch), and Median Lifetime (Tm)	Tbase = 85 °C, VDLO = 3.0 V, IDLO=260 mA, VD RF = 5.0 V, IDRF=360 mA, P _{diss} = 2.6 W	Tch = 136 °C Tm = 5.2 E+06 Hours



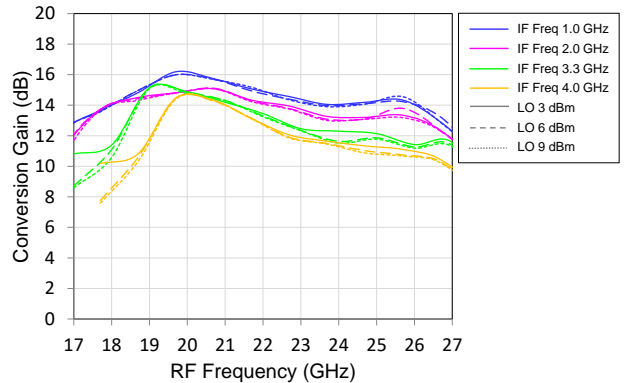
Performance Plots

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied

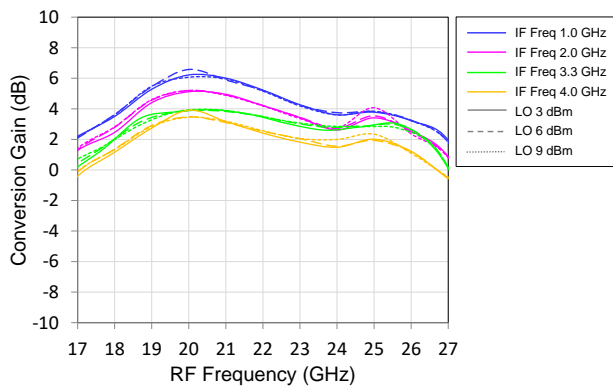
LSB Conversion Gain vs. RF vs. IF and LO Power
State: Max Gain



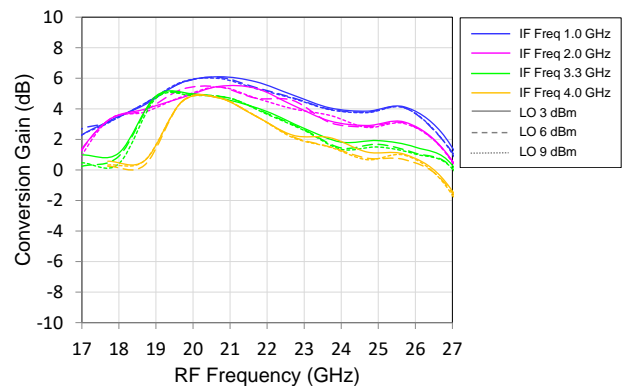
USB Conversion Gain vs. RF vs. IF and LO Power
State: Max Gain



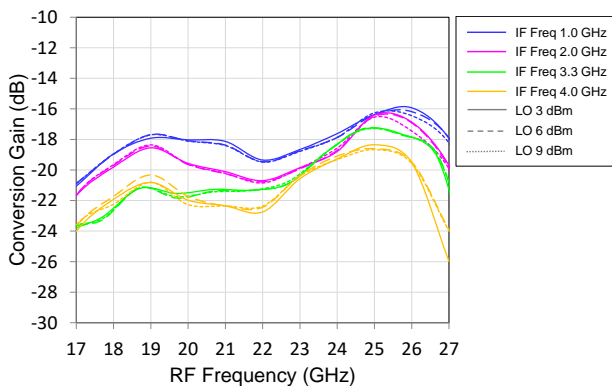
LSB Conversion Gain vs. RF vs. IF and LO Power
State: Reduced Gain



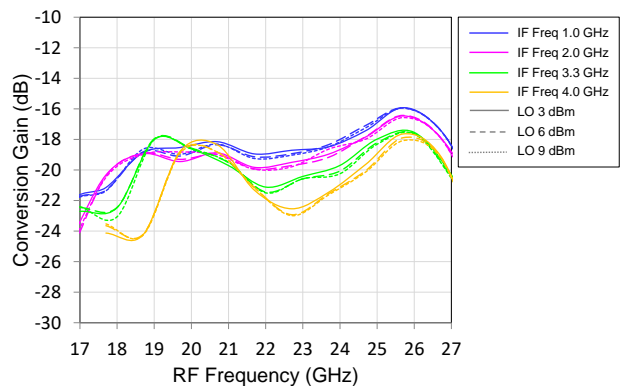
USB Conversion Gain vs. RF vs. IF and LO Power
State: Reduced Gain



LSB Conversion Gain vs. RF vs. IF and LO Power
State: Min Gain

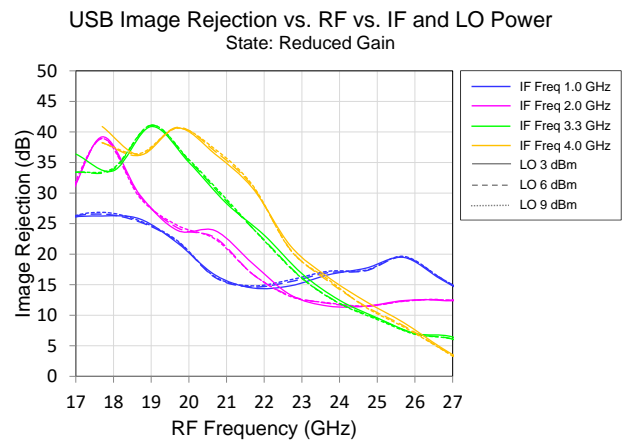
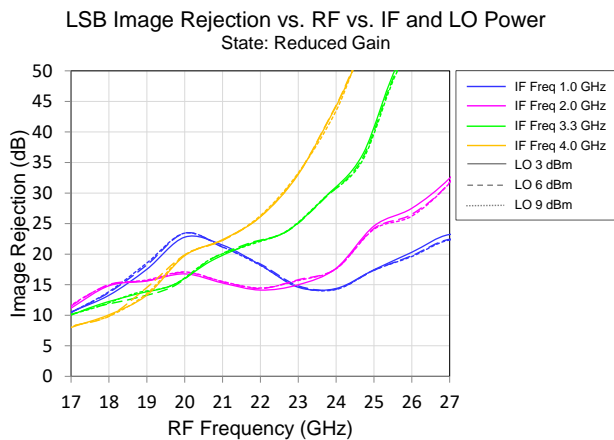
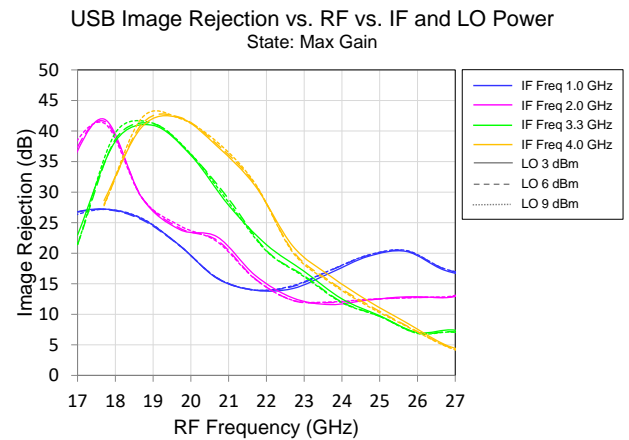
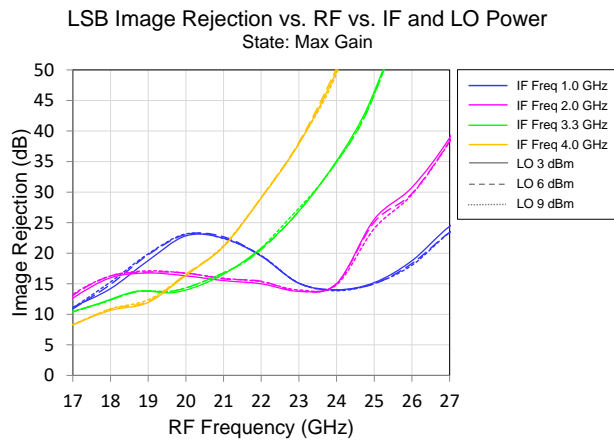
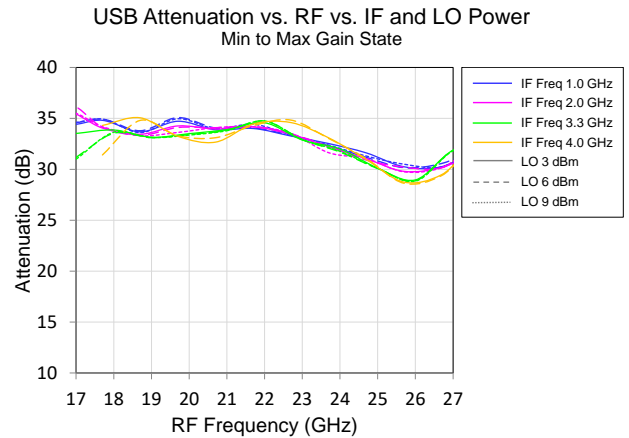
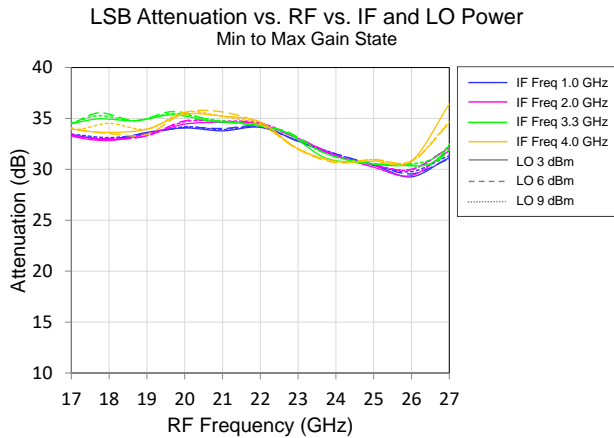


USB Conversion Gain vs. RF vs. IF and LO Power
State: Min Gain



Performance Plots

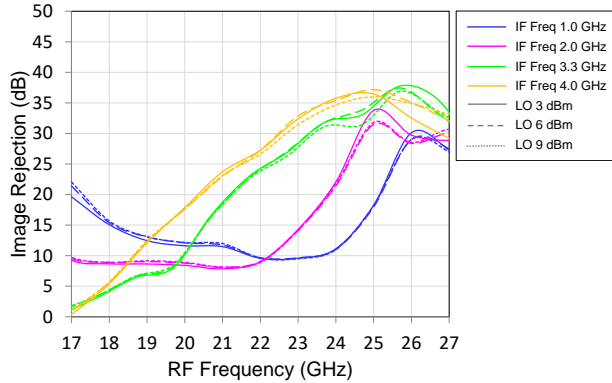
Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied.



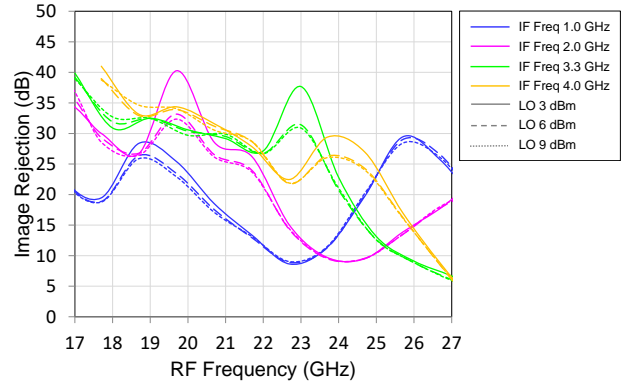
Performance Plots

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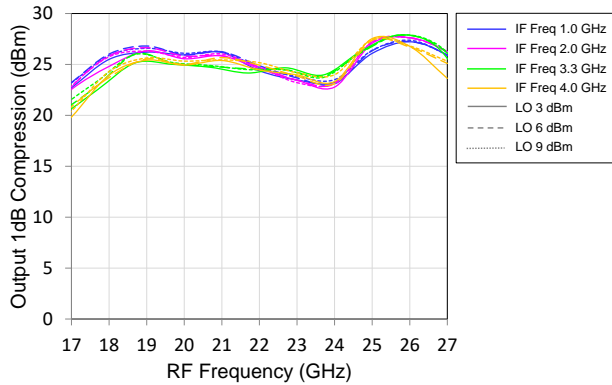
LSB Image Rejection vs. RF vs. IF and LO Power
State: Min Gain



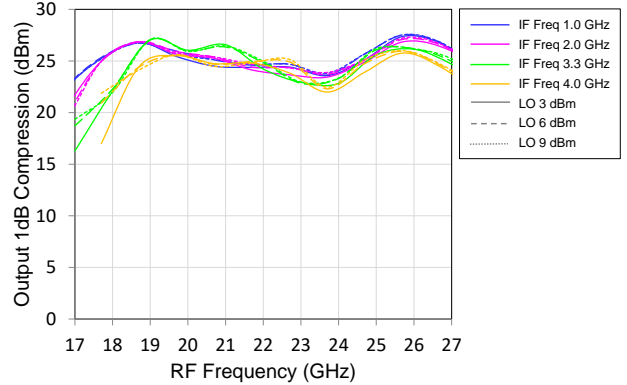
USB Image Rejection vs. RF vs. IF and LO Power
State: Min Gain



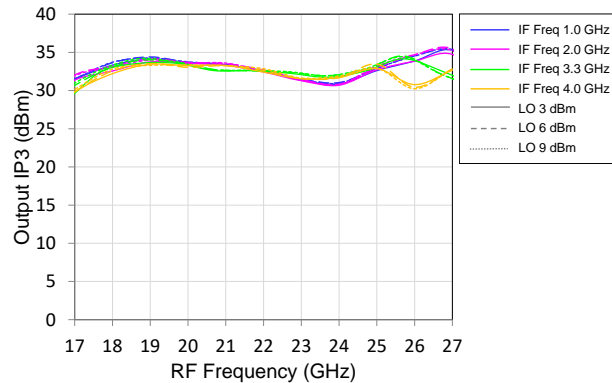
LSB Output P1dB vs. RF vs. IF and LO Power
State: Max Gain



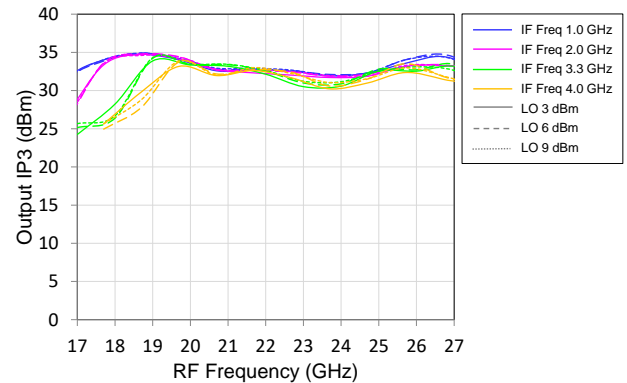
USB Output P1dB vs. RF vs. IF and LO Power
State: Max Gain



LSB Output IP3 vs. RF vs. IF and LO Power
State: Max Gain

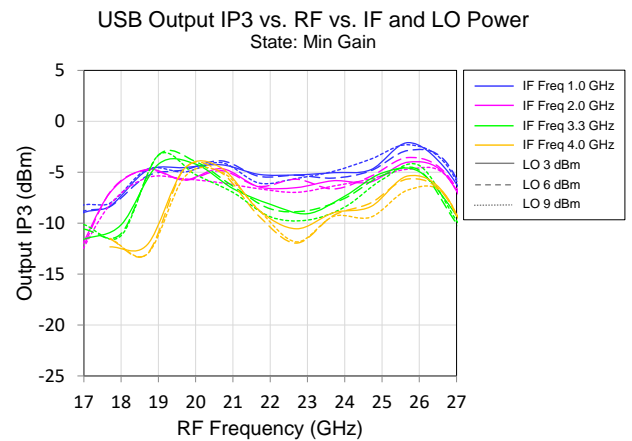
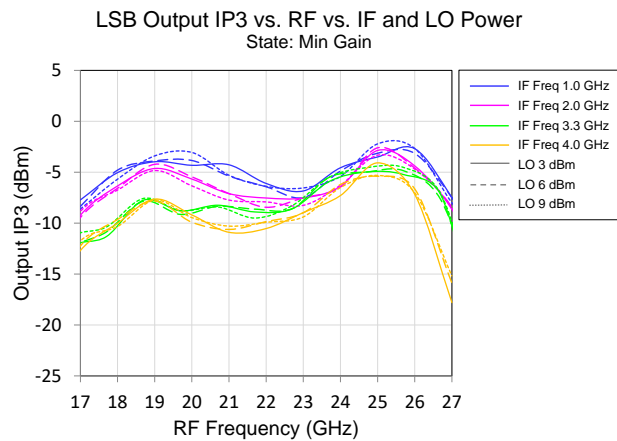
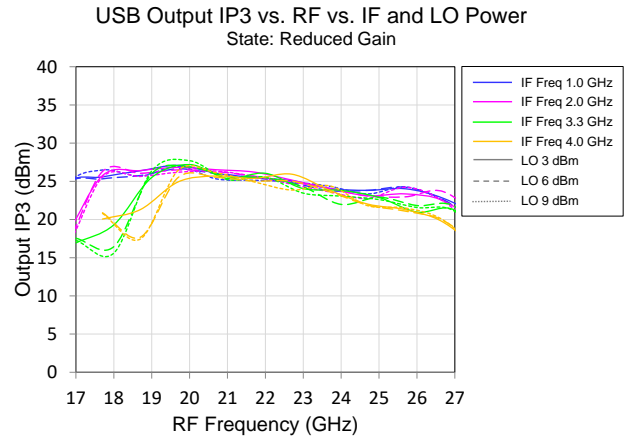
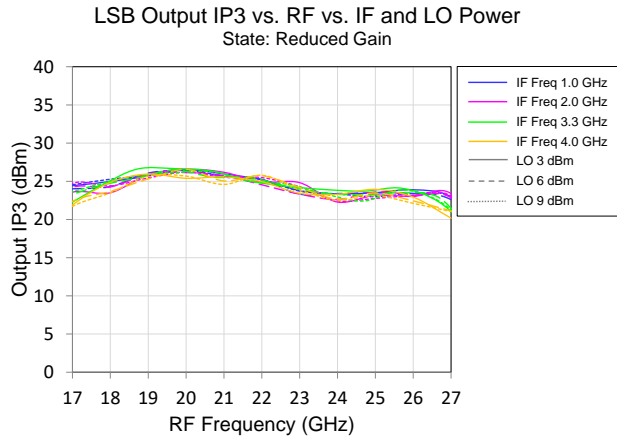


USB Output IP3 vs. RF vs. IF and LO Power
State: Max Gain



Performance Plots

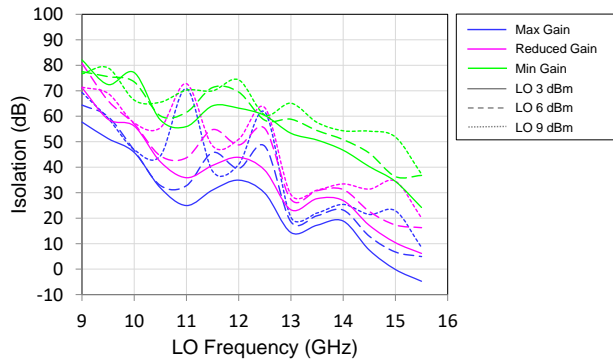
Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied.



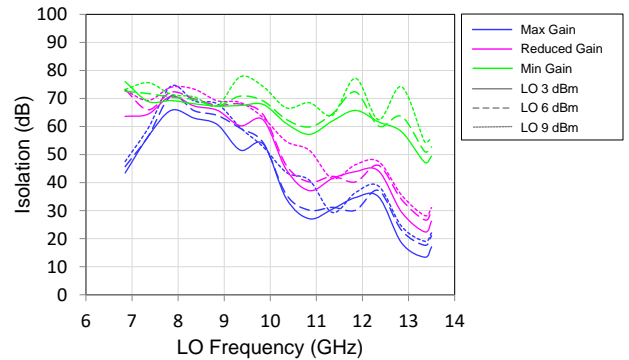
Performance Plots

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied.

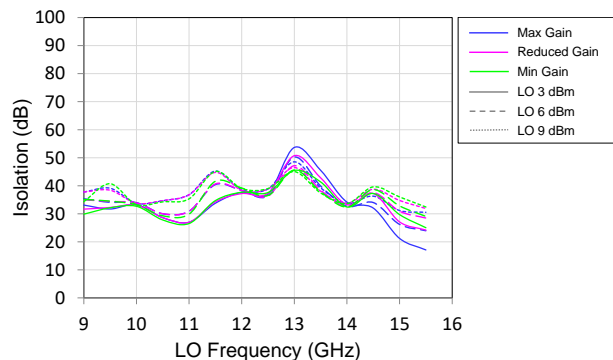
LSB LO-to-RF Isolation vs. LO Freq vs. LO Power and State



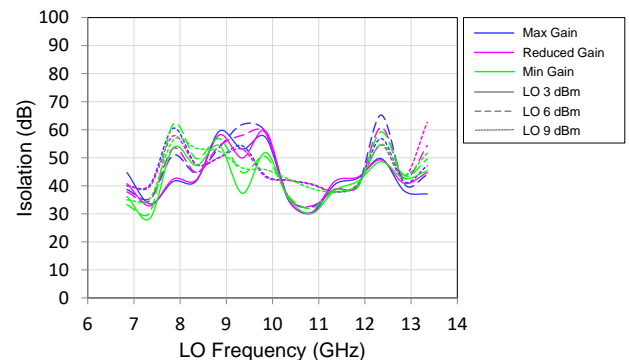
USB LO-to-RF Isolation vs. LO Freq vs. LO Power and State



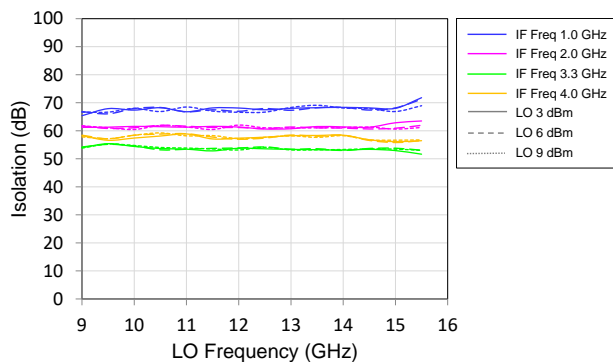
LSB LO-to-IF Isolation vs. LO Freq vs. LO Power and State



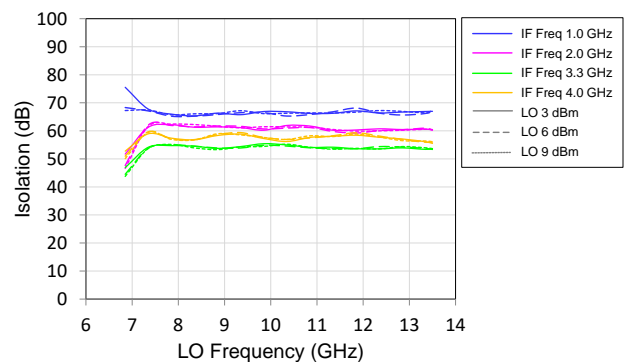
USB LO-to-IF Isolation vs. LO Freq vs. LO Power and State



LSB IF-to-RF Isolation vs. LO Freq vs. IF and LO Power
State: Max Gain



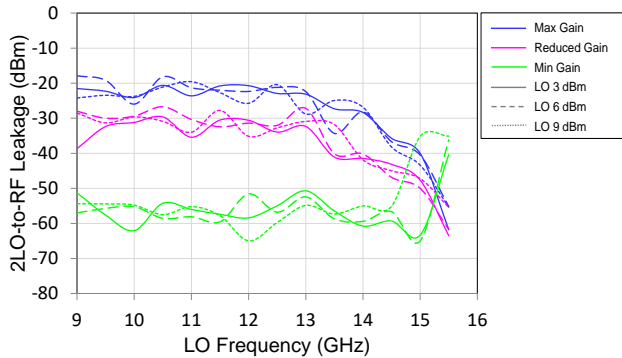
USB IF-to-RF Isolation vs. LO Freq vs. IF and LO Power
State: Max Gain



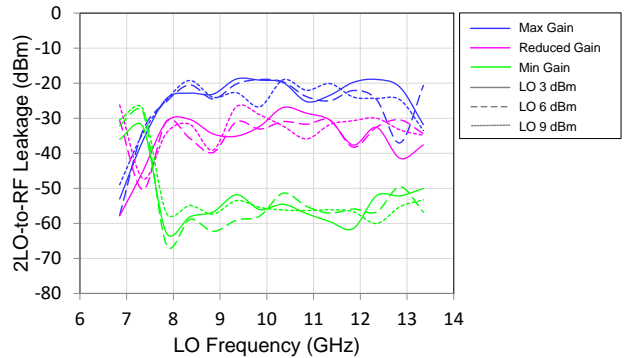
Performance Plots

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied.

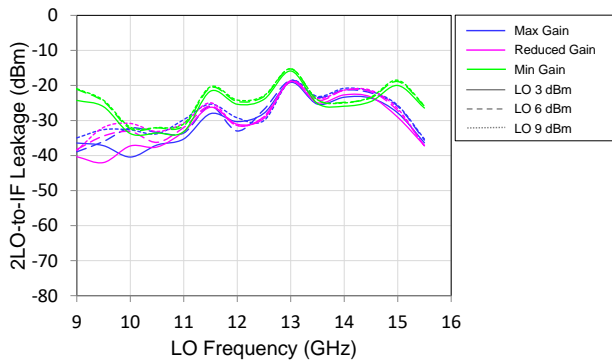
LSB 2LO-to-RF Leakage vs. LO Freq vs. LO Power and State



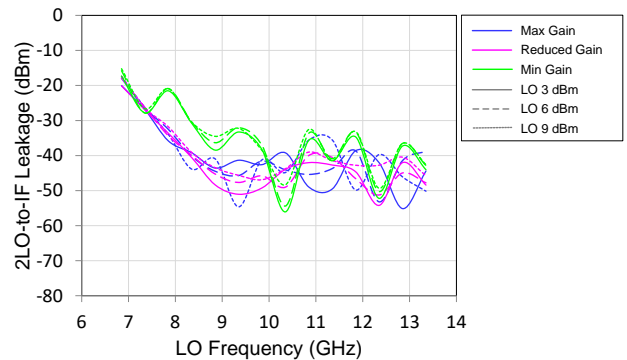
USB 2LO-to-RF Leakage vs. LO Freq vs. LO Power and State



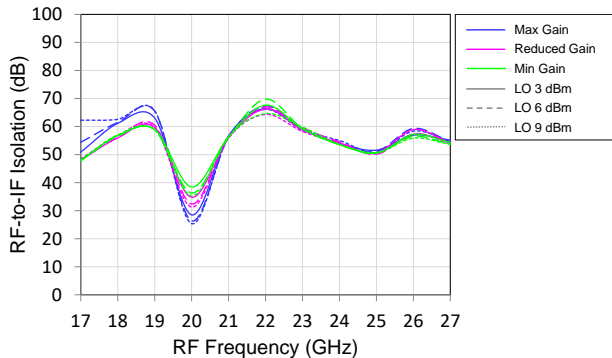
LSB 2LO-to-IF Leakage vs. LO Freq vs. LO Power and State



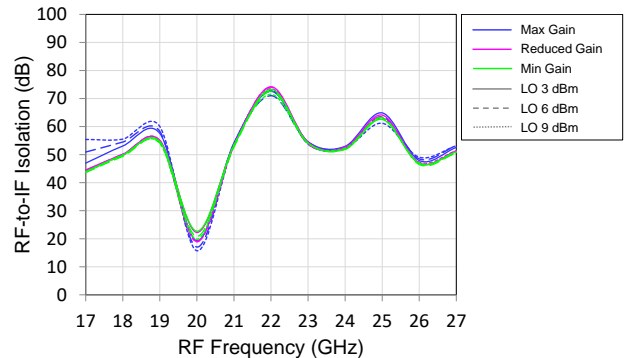
USB 2LO-to-IF Leakage vs. LO Freq vs. LO Power and State



RF-to-IF Isolation vs. RF Freq vs. LO Power and State
IF1 port, without external IF Hybrid

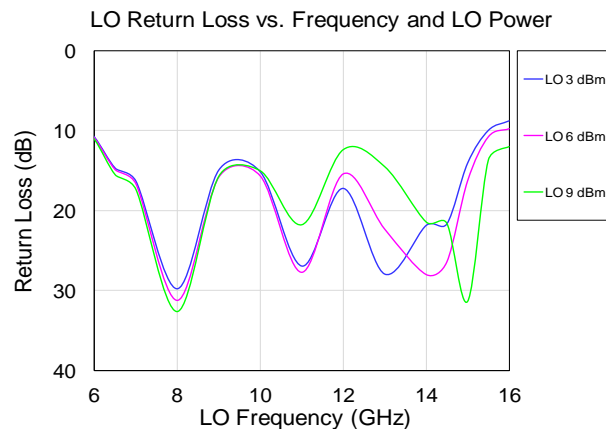
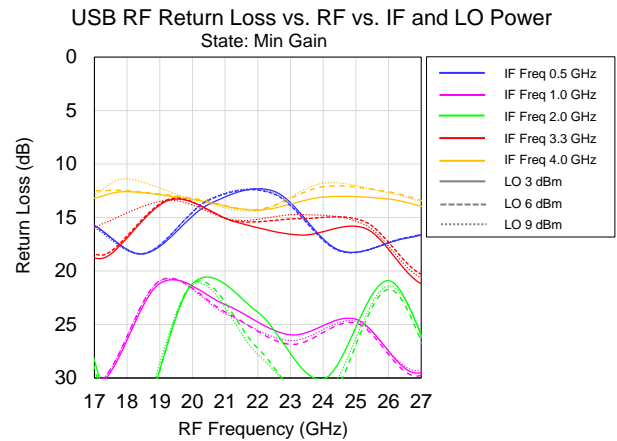
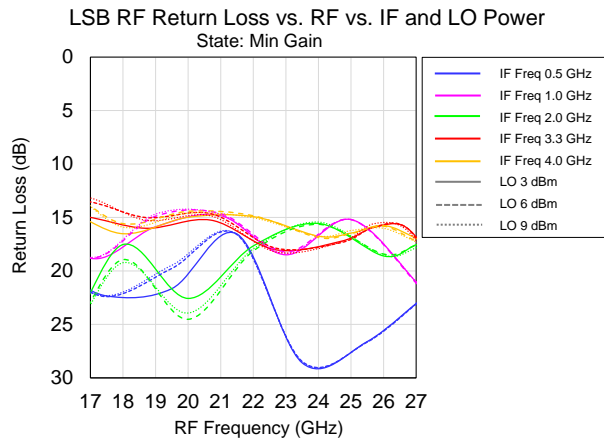
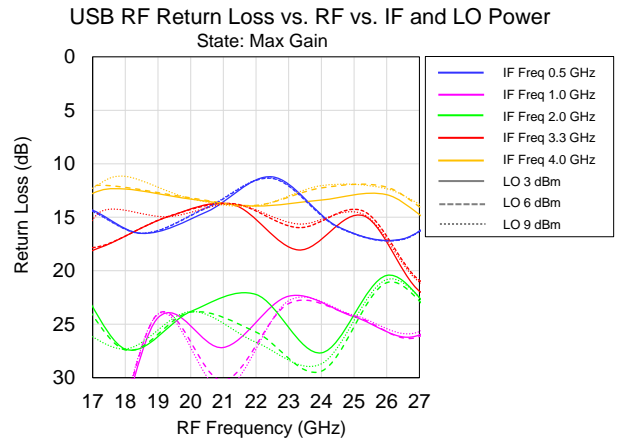
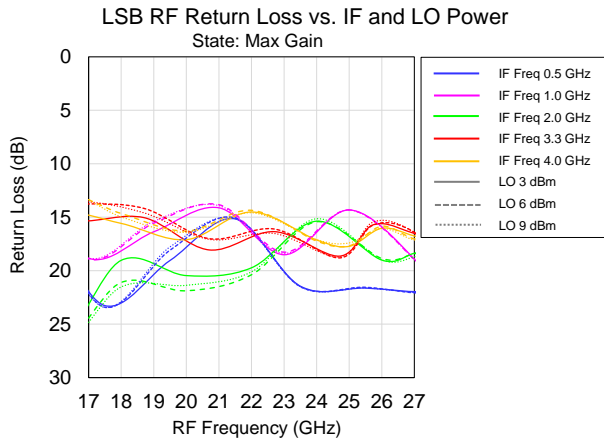


RF-to-IF Isolation vs. RF Freq vs. LO Power and State
IF2 port, without external IF Hybrid



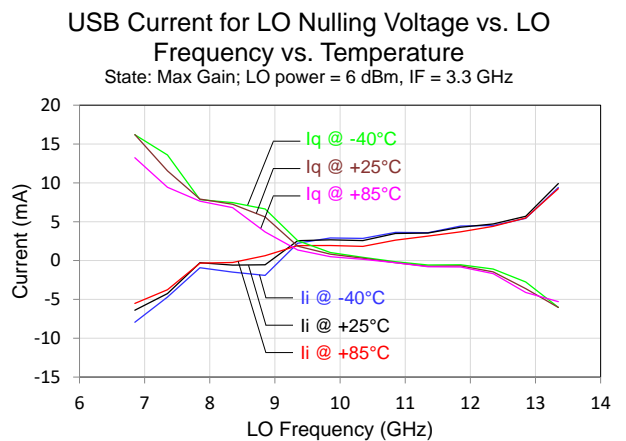
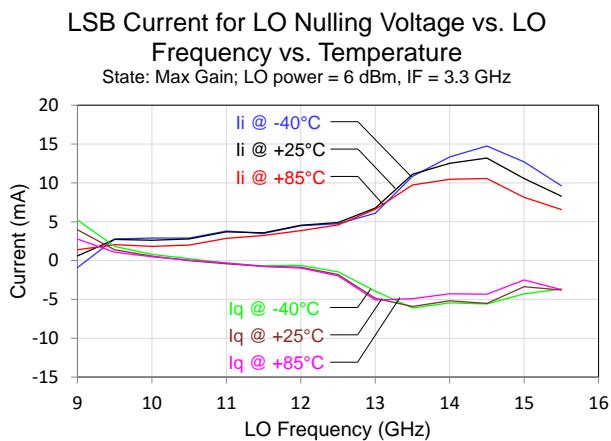
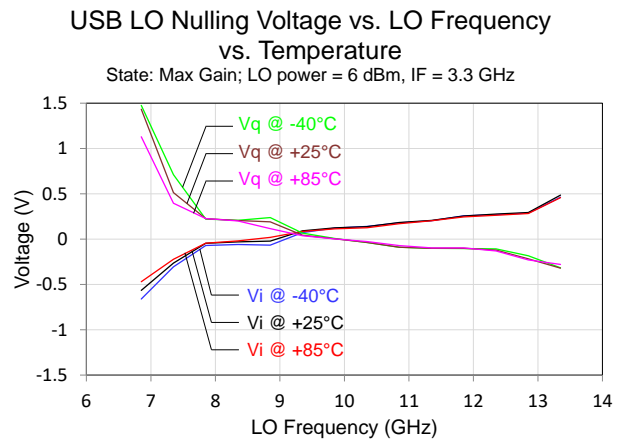
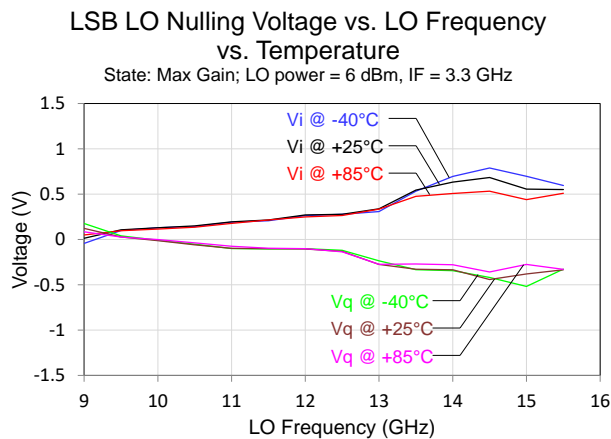
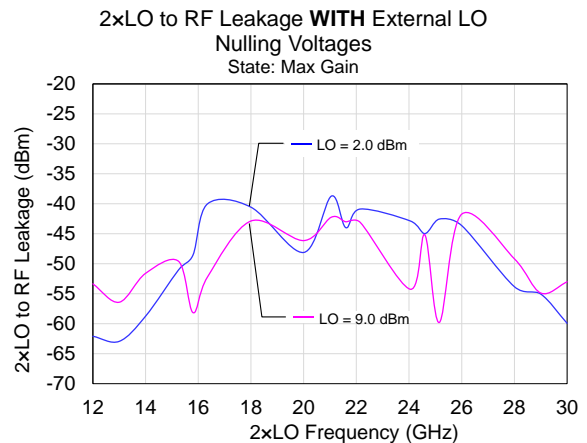
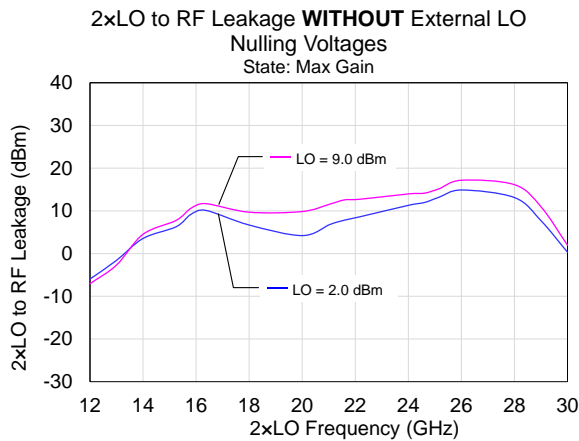
Performance Plots – Return Loss

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRF = 340 to 380 mA, VGX = - 1.2 V, 25 °C



Performance Plots - External LO Nulling

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = -0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = -0.75 V, IDRf = 340 to 380 mA, VGX = -1.2 V, 25 °C.

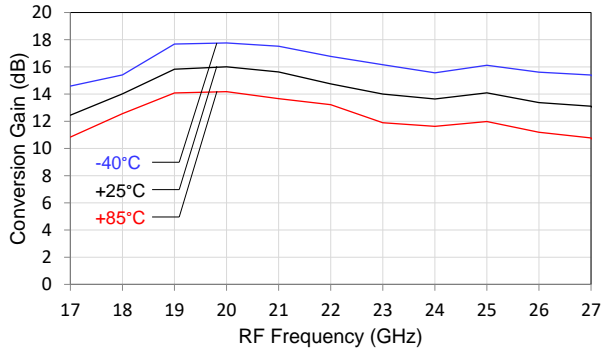


Performance Plots – Conversion Gain vs. Temperature

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRF = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied.

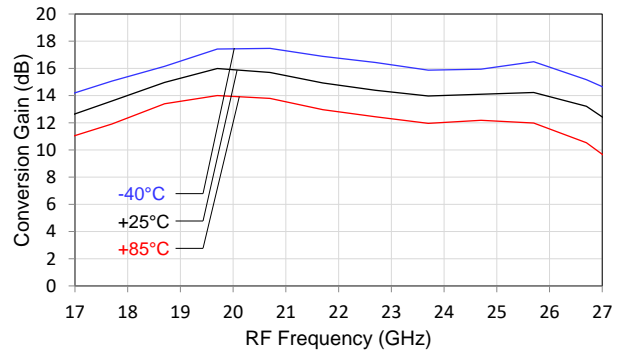
LSB Conversion Gain vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 1 GHz



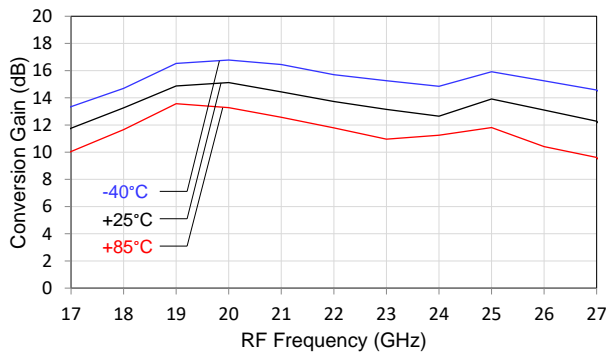
USB Conversion Gain vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 1 GHz



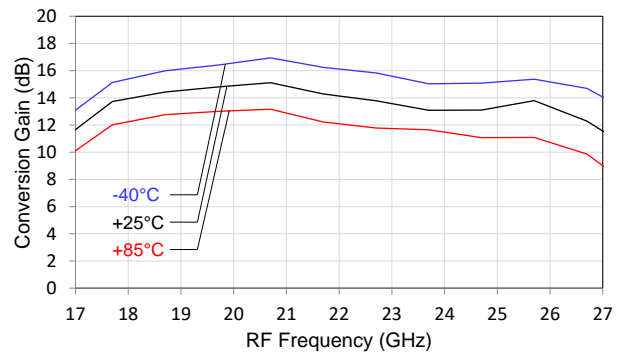
LSB Conversion Gain vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 2 GHz



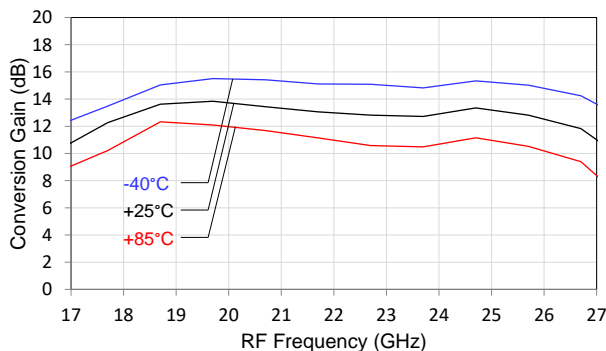
USB Conversion Gain vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 2 GHz



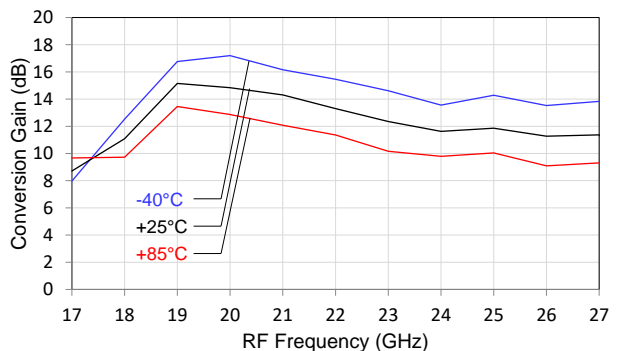
LSB Conversion Gain vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 3.3 GHz



USB Conversion Gain vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 3.3 GHz

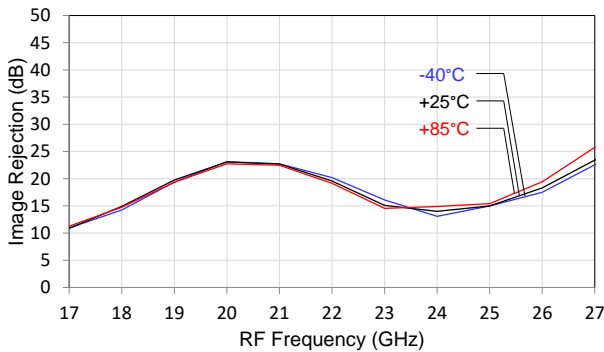


Performance Plots – Image Rejection vs. Temperature

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied

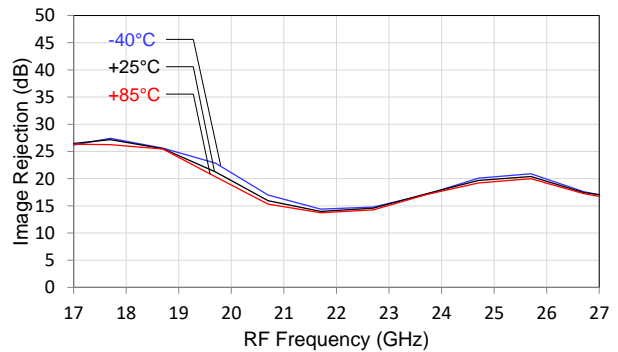
LSB Image Rejection vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 1 GHz



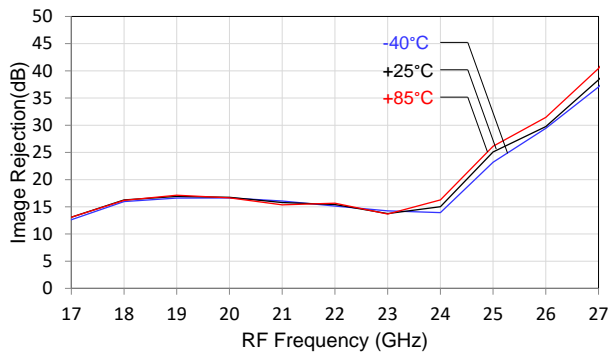
USB Image Rejection vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 1 GHz



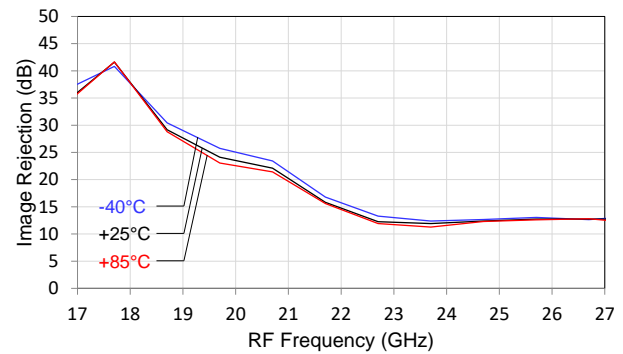
LSB Image Rejection vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 2 GHz



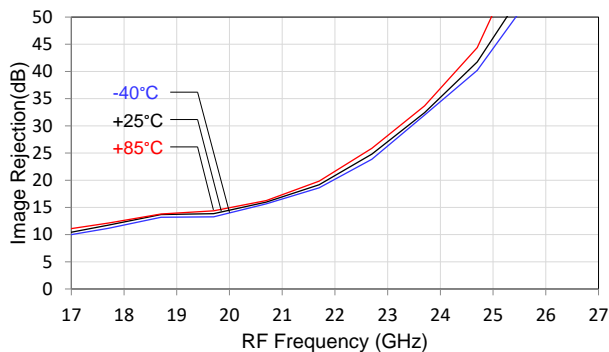
USB Image Rejection vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 2 GHz



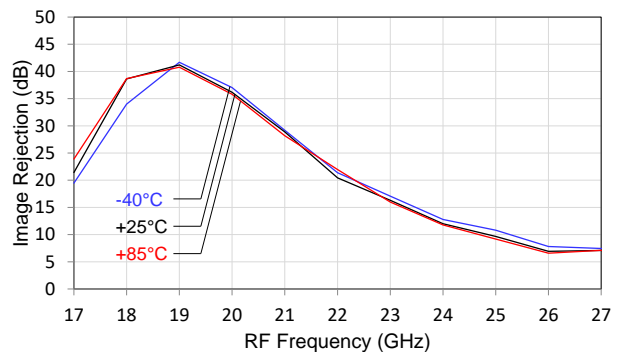
LSB Image Rejection vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 3.3 GHz



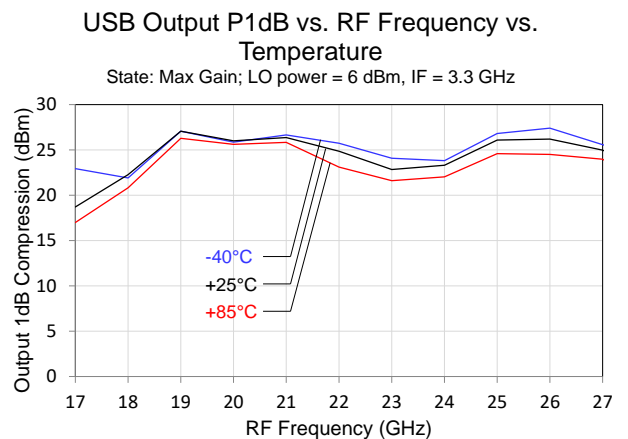
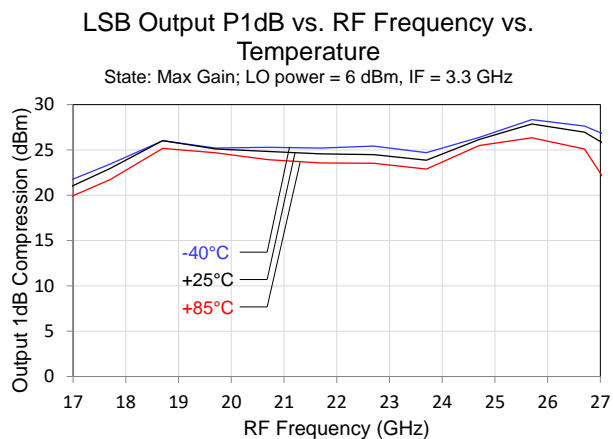
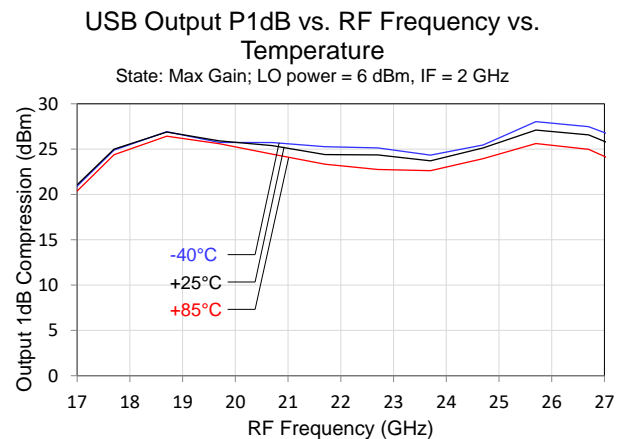
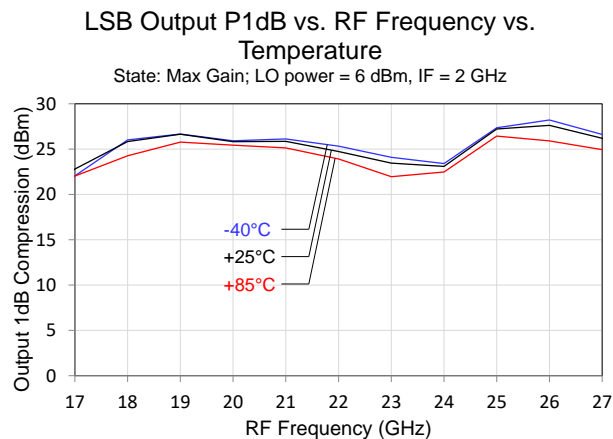
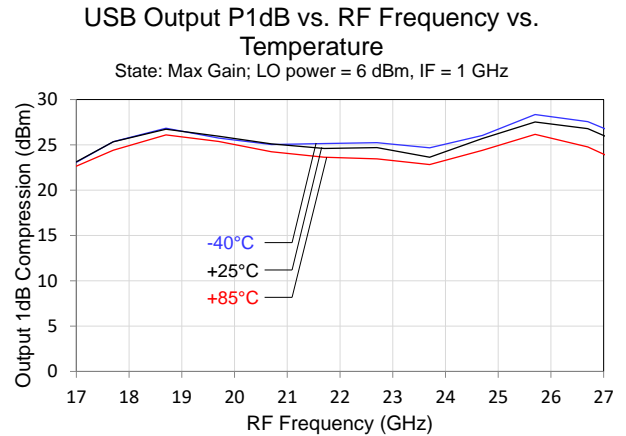
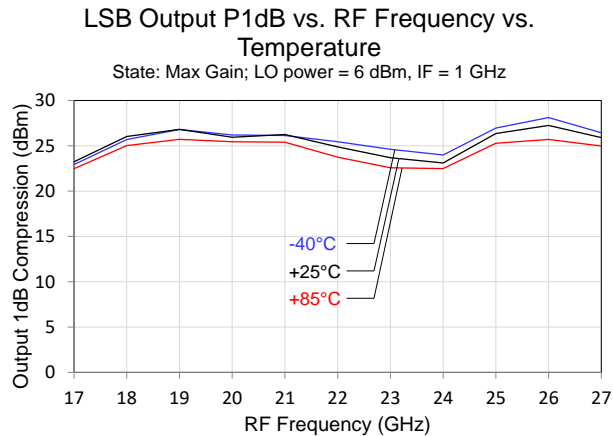
USB Image Rejection vs. RF Frequency vs. Temperature

State: Max Gain; LO power = 6 dBm, IF = 3.3 GHz



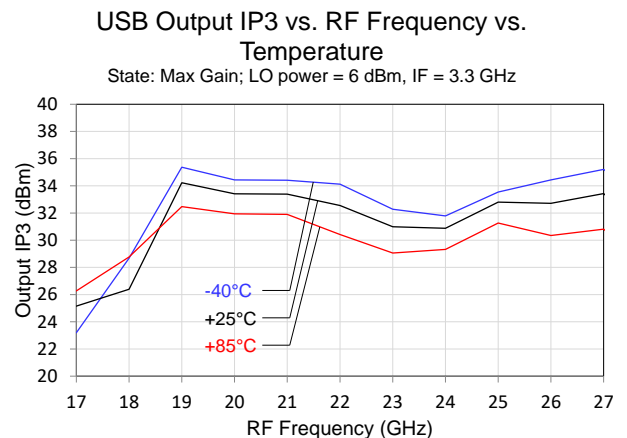
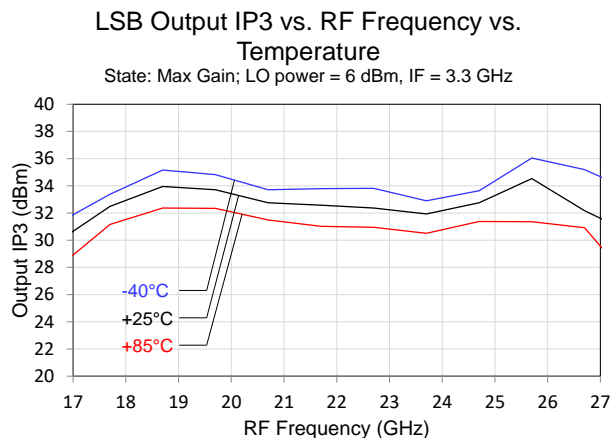
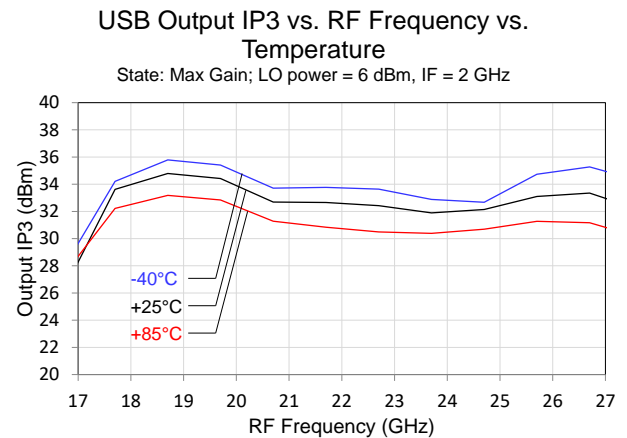
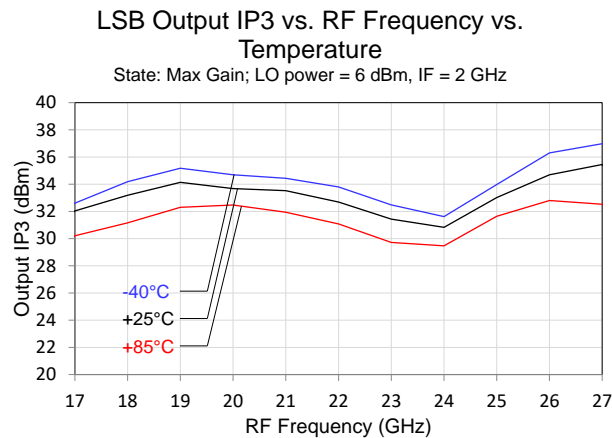
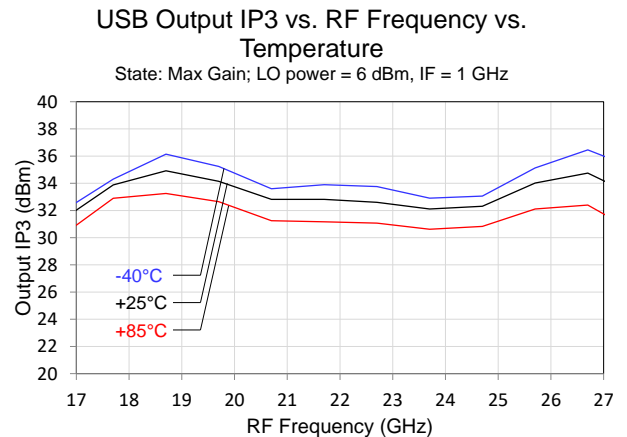
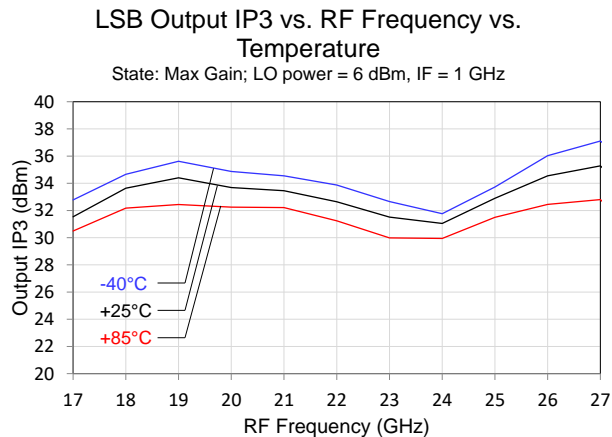
Performance Plots – 1dB Compression vs. Temperature

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied.



Performance Plots – Output IP3 vs. Temperature

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.5 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRf = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied.



Mixing Products

Test conditions unless otherwise noted: VDLO1, VDLO23 = 3.3 V, VGLO = - 0.7 V, IDLO1+IDLO23 = 140 to 200 mA, VDRF = 5.0 V, VGRF = - 0.75 V, IDRF = 340 to 380 mA, VGX = - 1.2 V, 25 °C. Data taken with external IF hybrid and LO nulling applied, 25 °C.

M x N Spurious Outputs for LSB

Spur tables are $N \times f_{IF} - M \times f_{LO}$ mixer spurious products. RF frequency is at $2 \times LO - IF$.

All values are in dBc below the RF output power level. IF input power = -10 dBm, LO Power = 3 to 9 dBm.

		M x f _{LO}					
		0	1	2	3	4	5
N x f _{IF}	-5	--	86	79	70	60	63
	-4	--	85	76	74	63	61
	-3	--	84	77	70	59	60
	-2	--	82	74	66	64	61
	-1	--	81	0	63	58	61
	0	--	12	19	4	33	53
	1	89	75	12	63	57	60
	2	83	75	73	61	61	57
	3	82	74	67	60	60	--
	4	79	76	69	63	60	--
5	84	77	67	59	58	--	

If = 2.0 GHz, LO = 9.0 GHz to 13.0 GHz

		M x f _{LO}					
		0	1	2	3	4	5
N x f _{IF}	-5	--	84	80	73	64	62
	-4	--	86	79	68	61	64
	-3	--	87	78	70	64	61
	-2	--	83	71	63	61	66
	-1	--	49	0	38	63	65
	0	--	-3	20	27	37	53
	1	75	37	11	61	62	--
	2	84	77	64	63	63	--
	3	83	75	62	60	58	--
	4	79	74	59	60	--	--
5	76	69	62	64	--	--	

IF = 3.3 GHz, LO = 10.0 GHz to 15.0 GHz

M x N Spurious Outputs for USB

Spur tables are $N \times f_{IF} - M \times f_{LO}$ mixer spurious products. RF frequency is at $2 \times LO + IF$.

All values are in dBc below the RF output power level. IF input power = -10 dBm, LO Power = 3 to 9 dBm.

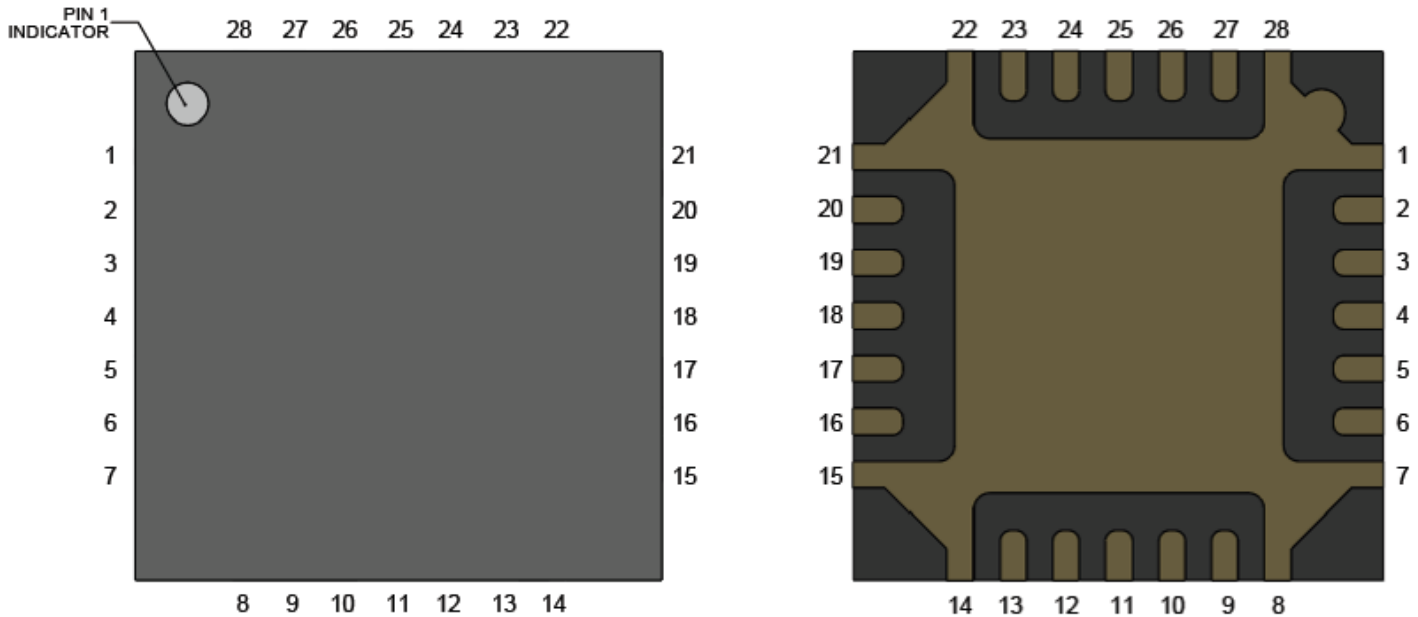
		M x f _{LO}					
		0	1	2	3	4	5
N x f _{IF}	-5	--	89	77	76	65	62
	-4	--	88	76	78	65	62
	-3	--	88	79	73	64	64
	-2	--	84	68	72	61	62
	-1	--	76	14	53	54	65
	0	--	26	-13	6	32	55
	1	69	59	0	42	61	63
	2	88	77	66	61	63	64
	3	85	79	74	64	59	66
	4	85	79	71	66	65	65
5	85	79	69	62	63	61	

If = 2.0 GHz, LO = 8.0 GHz to 12.0 GHz

		M x f _{LO}					
		0	1	2	3	4	5
N x f _{IF}	-5	--	84	87	77	74	61
	-4	--	85	82	77	74	66
	-3	--	88	79	79	69	63
	-2	--	86	72	74	55	63
	-1	--	78	10	43	21	51
	0	--	25	-14	1	-24	49
	1	59	52	0	35	33	63
	2	86	77	60	64	63	62
	3	85	78	69	63	61	62
	4	80	78	68	61	61	61
5	77	71	62	60	63	60	

IF = 3.3 GHz, LO = 11.0 GHz to 15.5 GHz

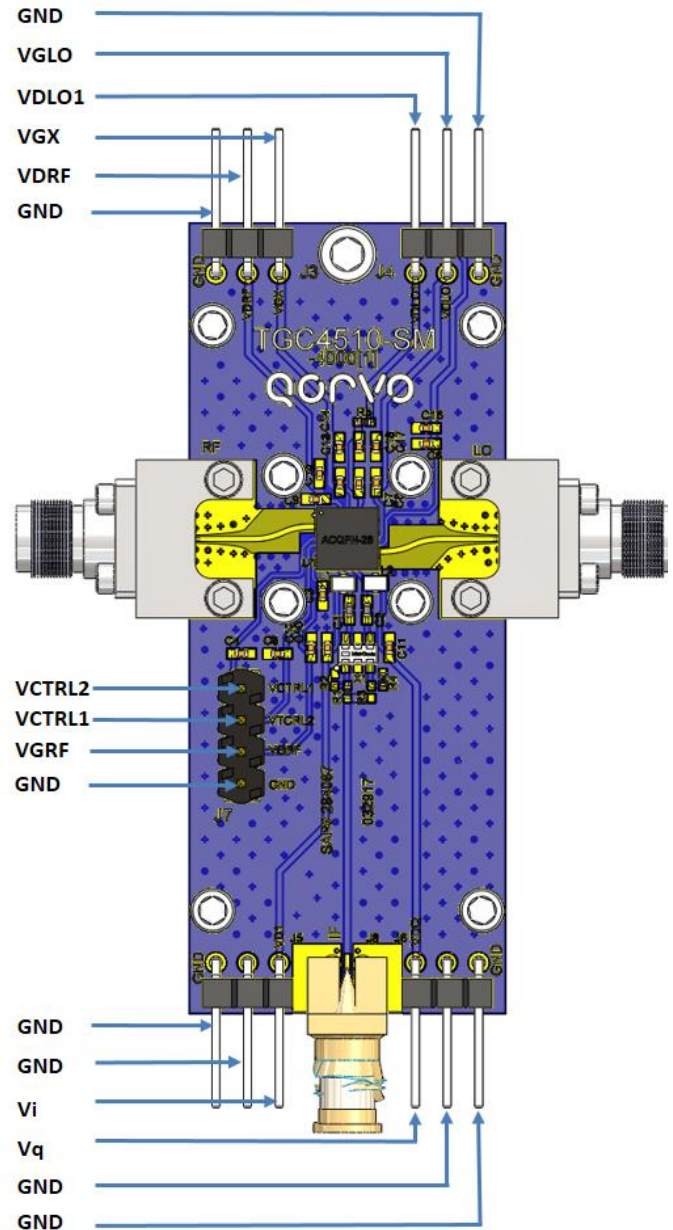
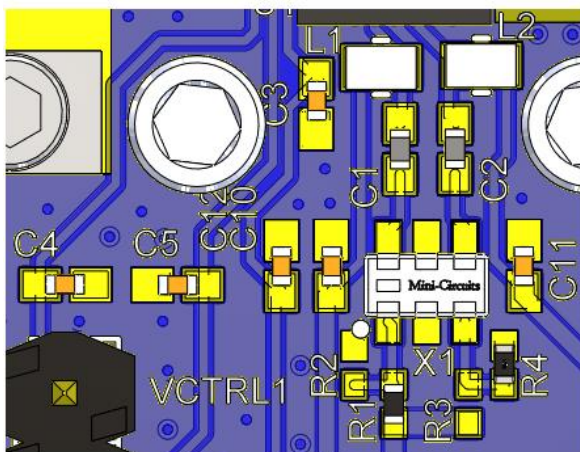
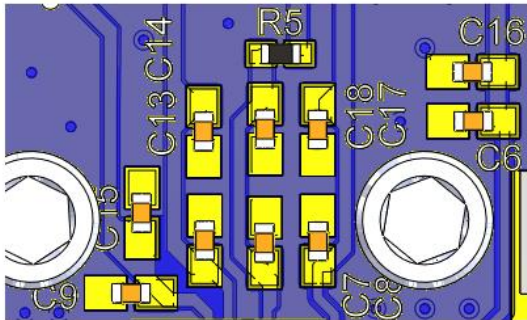
Pin Configuration and Description



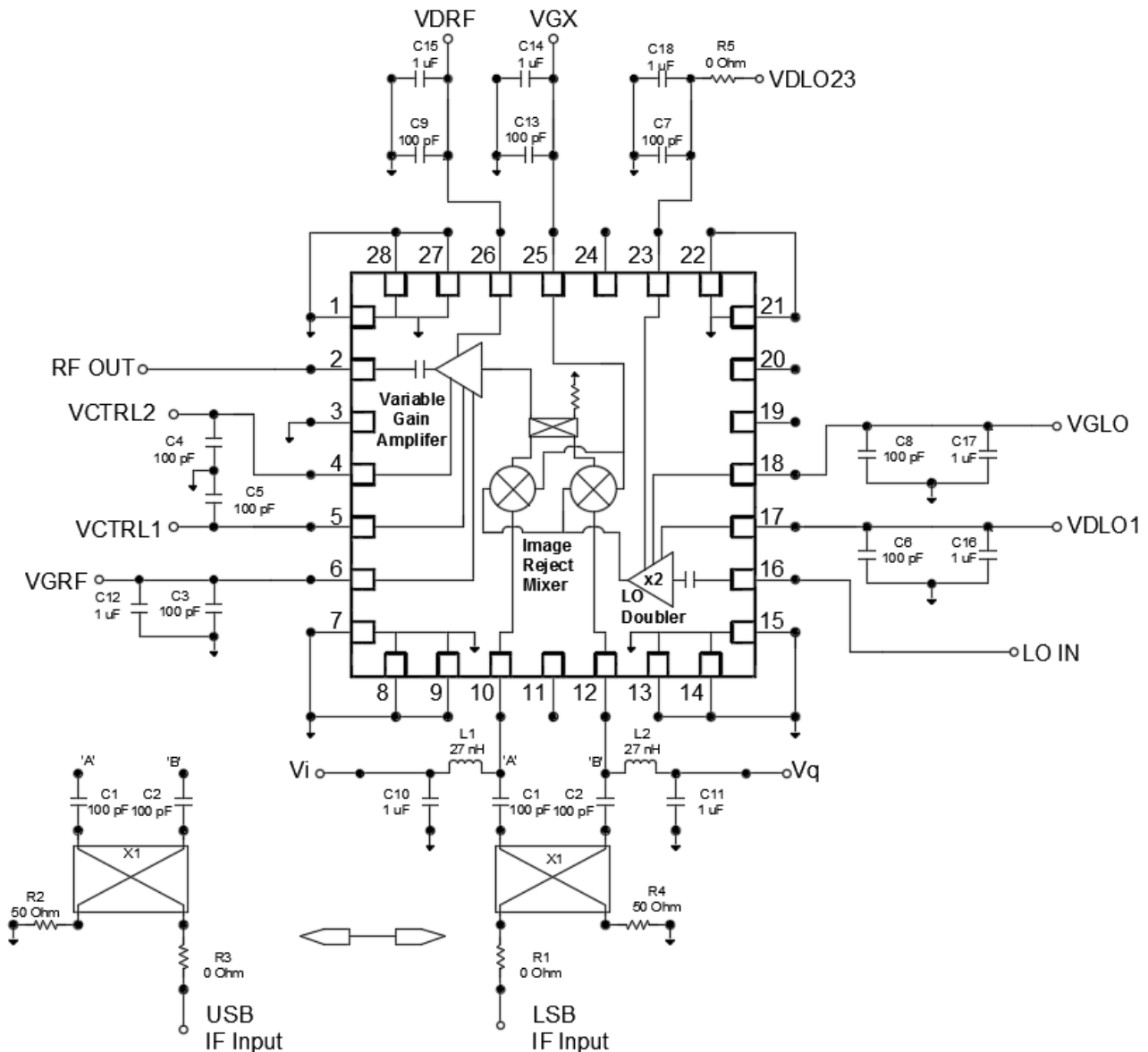
Pin No.	Label	Description
1, 7, 8, 9, 13, 14, 15, 21, 22, 27, 28	GND	Internal grounding; must be grounded on PCB.
2	RF OUT	RF Output matched to 50 ohms, AC Coupled.
3, 11, 19, 20, 24	NC	No internal connection; must be grounded on PCB.
4	VCTRL2	Variable gain control for RF amplifier
5	VCTRL1	Variable gain control for RF amplifier
6	VGRF	Gate voltage for RF amplifier
10	IF2	IF input for upconverter
12	IF1	IF input for upconverter
16	LO IN	LO input for upconverter.
17	VDLO1	Drain voltage for the first stage of the LO doubler
18	VGLO	Gate bias for VDLO1 and VDLO23.
23	VDLO23	Drain voltage for stages 2 and 3 of LO doubler
25	VGX	Mixer bias voltage
26	VDRF	Drain voltage for the RF amplifier
29	GND	Backside Paddle

Evaluation Board (EVB) Assembly Layout

Board material is single core layer using 0.008" thick Rogers RO4003, $\epsilon_r = 3.38$. Metal layer is 0.5-oz copper cladding.



Applications Circuit



Bias-up Procedure

Set VGX = -1.2 V, VCTRL1 = -2.0 V, VCTRL2 = 0 V, VGLO = -1.2 V, VGRF = -1.2 V. Set limit for each to 10mA.

Set VDRF = 5.0 V, limit 390 mA, VDLO1 and VDLO23 = 3.3 V. Set VDLO1 limit to 150 mA and VDLO23 limit to 200 mA or VDLO1+VDLO23 = 350 mA

Adjust VGLO to get IDLO1+IDLO23 to 180 mA.

Adjust VGRF to get RF amplifier current (VDRF) of 360 mA.

Apply LO and IF signals.

If using external control for LO nulling, adjust Vi and Vq for optimum LO suppression, adjust VCTRL1 and VCTRL2 to get required conversion gain.

Bias-down Procedure

Turn off IF and LO signals.

Set VDLO1, VDLO23 to 0 V.

Set VDRF to 0 V.

Set Vi, Vq to 0 V if used LO nulling.

Set VGLO, VGRF, VGX to 0 V.

Set VCTRL1, VCTRL2 to 0 V.

Application Circuit Components

Bill of Material

Ref Des	Value	Description	Manufacturer	Part Number
C1 – C9, C13	100 pF	Cap, 0603, 25 V, +/- 5%, NPO	various	
C10 – C12, C14 – C18	1 μ F	Cap, 0603, 25 V, 10%, X7R	various	
L1 – L2	27 nH	Ind, 0603, 2%, 0.6A, SMD	various	
R5	0 Ω	Res, 0402, 1/10 W, 5%, SMD	various	
Q1		Ku-Band Up-Converter	QORVO	TGC4510-SM

LSB Configuration

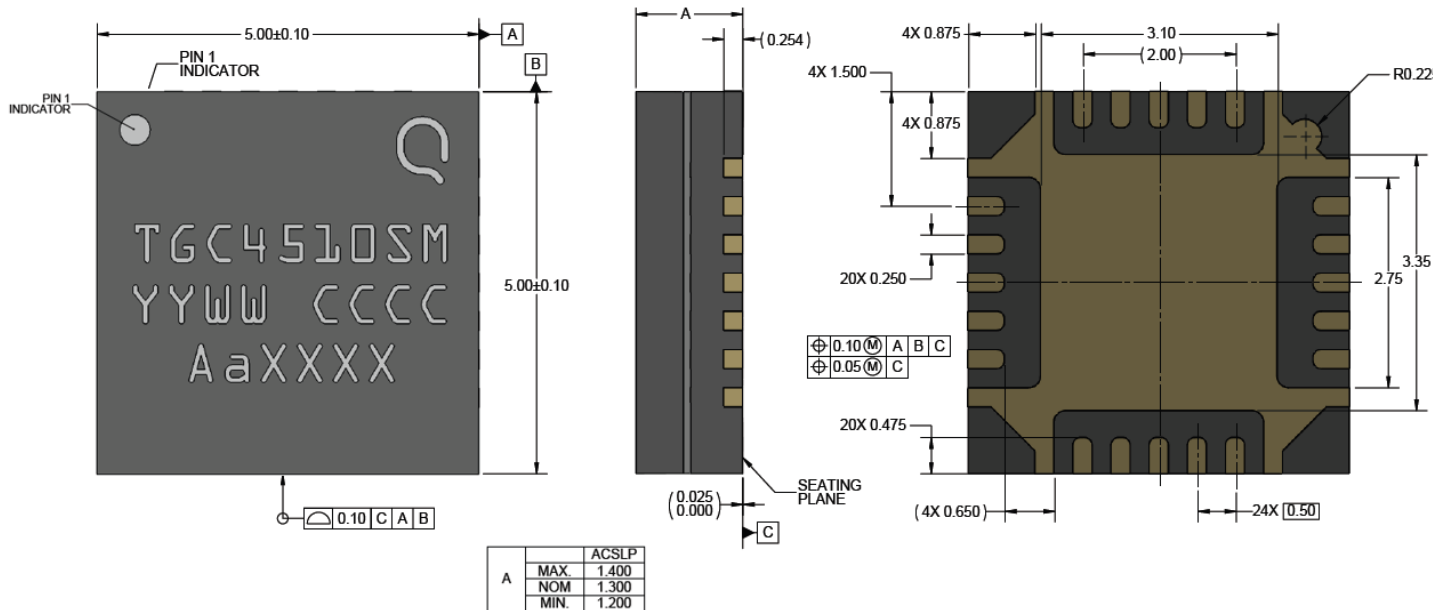
Ref Des	Value	Description	Manufacturer	Part Number
X1 (For Low IF)		IF Quad Coupler, 1.35 to 2.45 GHz	Mini-Circuits	QCN-25+
X1 (For High IF)		IF Quad Coupler, 2.5 to 4.0 GHz	Mini-Circuits	QCN-45+
R1	0 Ω	Res, 0402, 1/10 W, 5%, SMD	various	
R4	50 Ω	Res, 0402, 1/8 W, 1%, SMD	various	
R2, R3		DNP		

USB Configuration

Ref Des	Value	Description	Manufacturer	Part Number
X1 (For Low IF)		IF Quad Coupler, 1.35 to 2.45 GHz	Mini-Circuits	QCN-25+
X1 (For High IF)		IF Quad Coupler, 2.5 to 4.0 GHz	Mini-Circuits	QCN-45+
R3	0 Ω	Res, 0402, 1/10 W, 5%, SMD	various	
R2	50 Ω	Res, 0402, 1/8 W, 1%, SMD	various	
R1, R4		DNP		

Note: Due to bandwidth limitations of IF quad coupler, two versions of coupler were used on EVBs, users need to choose low or high band of IF to be used, in addition to LSB and USB selection. Refer to ordering information section for details.

Package Marking and Dimensions



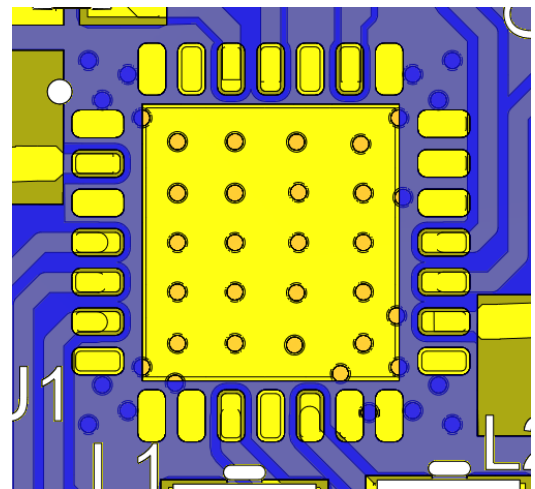
All dimensions are in millimeters. Top marking: “YY” represents the last two digits of the year the part was manufactured, the “WW” is the work week, CCCC is country code and the “XXXX” is batch ID.

This package is lead-free/RoHS-compliant with a copper alloy base (CDA194), and the plating material on the leads is NiPdAu. It is compatible with a lead-free (maximum 260 °C reflow temperature) soldering process.

PCB Mounting Pattern

Notes:

1. The pad pattern shown has been developed and tested for optimized assembly at Qorvo. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.
2. Ground / thermal vias are critical for the proper performance of this device. Vias should use a .35mm diameter drill and have a final plated thru diameter of .25 mm.

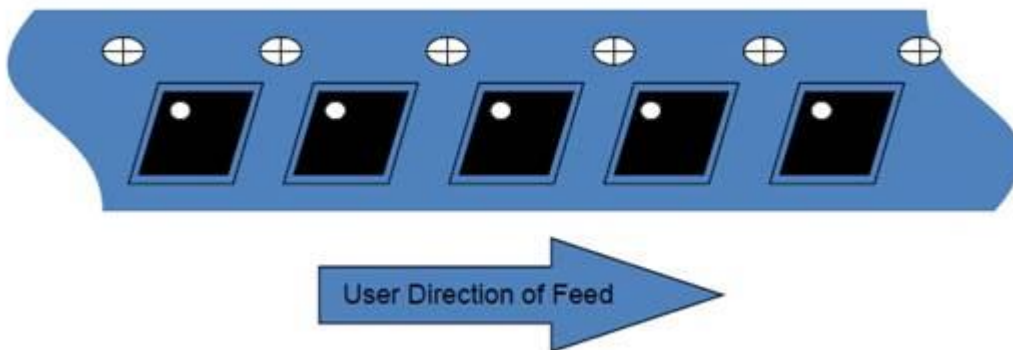
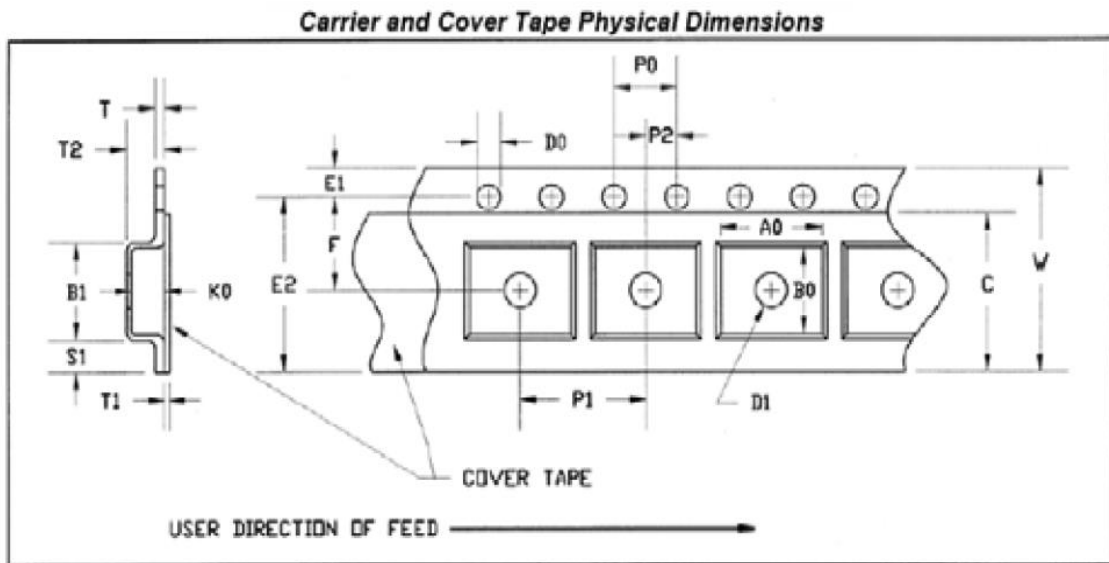


Tape and Reel Information

Standard T/R size = 500 pieces on a 7" reel. Tape and reel specifications for this part are also available on the QORVO website in the "Application Notes" section.

Carrier and Cover Tape Dimensions:

Part	Feature	Symbol	Size (in)	Size (mm)
Cavity	Length	A0	0.209	5.3
	Width	B0	0.209	5.3
	Depth	K0	0.064	1.65
	Pitch	P1	0.315	8.00
Cover Tape	Width	C	0.362	9.2
Carrier Tape	Width	W	0.472	12.00



Assembly Notes

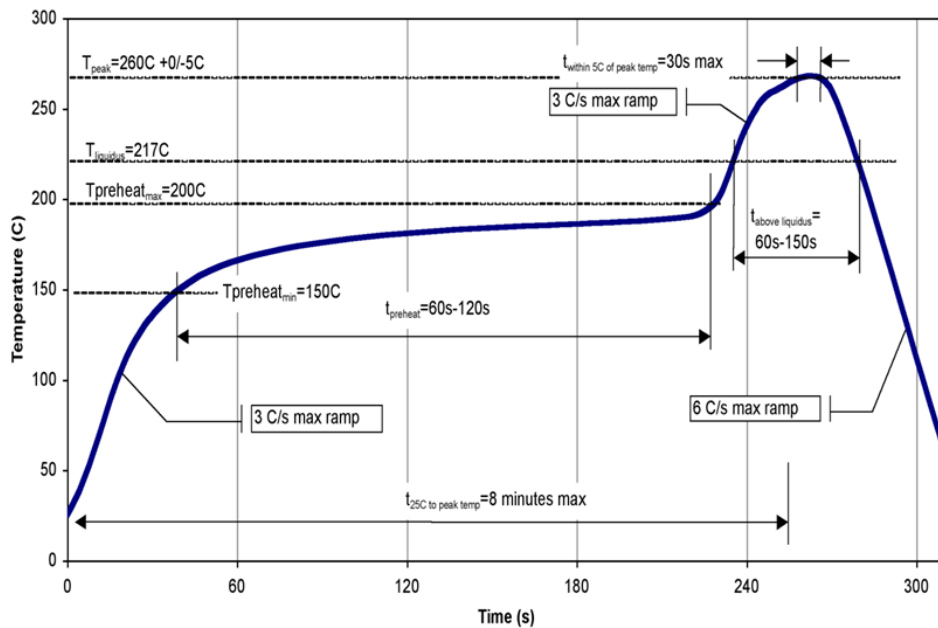
Compatible with lead-free soldering processes with 260°C peak reflow temperature.

This package is air-cavity and non-hermetic, and therefore cannot be subjected to aqueous washing. The use of no-clean solder to avoid washing after soldering is highly recommended.

Contact plating: Ni-Pd-Au.

Solder rework not recommended.

Recommended Soldering Temperature Profile



Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1A	ESDA / JEDEC JS-001-2012
MSL – Moisture Sensitivity Level	Level 1	IPC/JEDEC J-STD-020



Caution!
ESD-Sensitive Device

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances Electrical and Electronic Equipment), as amended by Directive 2015/863/EU. This product also has the following attributes

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Tel: 1-844-890-8163

Web: www.qorvo.com

Email: customer.support@qorvo.com

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